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Computer modeling of processes of radiation defection formation in aluminum irradiated by ions

Abstract. The article considers the process of interaction of ions with aluminum and the formation of the radiation defects. The selection of an approximate expression for the interaction cross section is found and the approximation coefficients are found. Algorithms of calculation of a cascade probability function, range of the primary beaten-out atoms, concentration of radiation defects are given. Calculations of cascade probability functions depending on number of interactions and a depth of penetration of particles, ranges of the primary beaten-out atoms (PKA), concentration of radiation defects are made. Regularities of behavior and finding of area of result when calculating cascade probability functions depending on number of interactions and a depth of penetration defects for the aluminum irradiated with ions are received. It is necessary to consider various factors: types of flying particles (charged and uncharged, light and Heavy), a real "physical" picture; i.e. processes occurring at interaction of particles with a substance.

Key words: ion, aluminium, approximation, algorithm, calculation, cascade-probabilistic function, the concentration of radiation defects.

Introduction

Modern development of science and technology requires the creation of fundamentally new materials that meet the requirements of various fields of energy. These materials should possess qualitatively new physical and chemical properties that assumes a detail study of structure of materials under the influence of the ionizing radiation and obtaining the defect information in structure of materials. A consequence of the action of ionizing radiation is a sharp change in their properties. Predicting the behavior of materials under harsh operating conditions requires the creation of quantitative models explaining radiation defect formation [1-8].

It is necessary to consider various factors: types of flying particles (charged and uncharged, light and Heavy), a real "physical" picture; i.e. processes occurring at interaction of particles with a substance. Aluminium is taken in the work. Aluminium and its alloys are increasingly used in shipbuilding Aluminum alloys are used for manufacturing ship hulls, deck superstructures, communication and various types of ship equipment. The main characteristics of aluminum and its alloys, revealing the expediency of their application in railway transport, high specific strength, small force of inertia, corrosion resistance. The introduction of aluminum alloys in the manufacture of welded tanks increases their durability in the transportation of a number of products of the chemical and petrochemical industry. One of the main requirements for materials used in road transport is low weight and relatively high strength. The corrosion resistance and good decorative surface of the material are also taken into consideration. The high specific strength of aluminum alloys increases the carrying capacity and reduces the operating costs of mobile transport. High corrosion resistance of the material extends

service life, expands the range of transported goods, including liquids and gases with high aggressive concentration.

The work is performed within the framework of a cascade-probabilistic method, the essence of which is to obtain and further use of cascadeprobability functions (CPF) having the sense of the probability of reaching a particle of a certain depth h after the n-th number of collisions [9-11].

Main results

The cascade probability function for ions has the following form [11]:

$$\psi_{n}(h',h,E_{0}) = \frac{1}{n!\lambda_{0}^{n}} \left(\frac{E_{0}-kh'}{E_{0}-kh}\right)^{-l} \exp\left(\frac{h-h'}{\lambda_{0}}\right) * \left[\frac{\ln\left(\frac{E_{0}-kh'}{E_{0}-kh}\right)}{ak} - (h-h')\right]^{n}.$$
(1)

where h',h – depth of generation and registration of the particle, respectively, n – number of interactions, E₀ the initial energy of the primary particle, σ_0 , *a*, *E*₀, *k* – approximation coefficients, $\lambda_0=1/\sigma_0$, $l=1/(\lambda_0 ak)$. Calculation of CPF is performed according to the formula:

$$\psi_{n}(h',h,E_{0}) = \exp\left[-\ln(n!) - n*\ln(\lambda_{0}) - \frac{1}{\lambda_{0}ak}\ln\left(\frac{E_{0} - kh'}{E_{0} - kh}\right) + \frac{h - h'}{\lambda_{0}} + n*\ln\left(\frac{\ln\left(\frac{E_{0} - kh'}{E_{0} - kh}\right)}{ak} - (h - h')}\right)\right],$$
(2)

In order to calculate the KPF by formula (2), it is necessary to find coefficients of approximation σ_0 , *a*, E_0 , *k* included in this expression. For this purpose, the interaction cross section is calculated by the Rutherford formula [12] there are depths of penetration from the tables of parameters of spatial distribution of ion-implanted impurities of Kumakhov-Komarov [13], the calculated section values are approximated with the following expression:

$$\sigma(h) = \sigma_0 \left(\frac{1}{a(E_0 - kh)} - 1 \right) \tag{3}$$

η

0.99285

0.99359

0.99282

0.99698

0.99852

Then the approximation coefficients for the various ions in the aluminium have been found. Table 1 shows the approximation parameters for indium in aluminium. The results of the approximation selection are shown in figure 1.

1.2488

60.56595

440.66742

 E_0 $\sigma_0 \times 10^9$ α $E_0^{'}$ K1000165.948062.071650.001840.13615800176.932260.961970.004270.20159

0.75709

0.2588

0.1165

Table 1 – Approximation values for indium in aluminum

226.59381

290.18127

408.7585

500

200

100

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0.00928

0.03555

0.10402

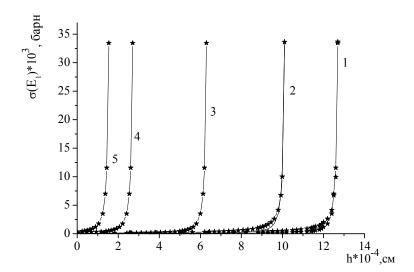


Figure 1 – Approximation of the modified section of the cascade-probability function for indium in aluminum $E_0=1000(1), 800(2), 500(3), 200(4), 100(5)$ keV. Points – calculated data of the dependence of the cross section on depth, solid line – approximation

Further calculations of the CPF have been performed as a function of the number of interactions (Table 2) and the penetration depth of the particles (Table 3).

The regularities in the behavior of the result area and the step for calculation for the CPF, calculated as a function of the number of interactions during irradiation of aluminum by ions, are revealed.

1. At a small atomic weight of the incident particle and small depths, the maximum value of the CVF is reached approximately at h/λ . With increasing depth observation area of the result begins to shift in the area of small depths of the respective h/λ . and narrow.

2. When the initial energy decreases (the particle and the target are the same) at the same depth the area of the result is also narrowed and shifted to the area of small depths.

3. As the atomic weight of the incident particle increases, the range of the result shifts to a region of shallow depths with respect to h/λ and narrows.

4. At a large atomic weight of the incident particle, the maximum value of the CPF shifts to a region of shallow depths relative to h/λ already at shallow depths, and at large depths the result is in a narrow region (less than 1%, silver, gold).

5. The narrowest area of the result is obtained

with a large atomic weight of the incident particle and a small target at the end of the run and reaches hundredths of a percent. At the same time the account is growing strongly.

Since h/λ can be very large (tens of millions), then the values of the CPF, calculated in steps of 1, will not practically differ from each other and the counting time will be very long (more than two hours). The step takes some value N_n , that is added to the current n and KVF is calculated at n, $n+N_n$, $n+2N_n$... Thus for calculating the CPF, it is necessary to find not only the area for determining the result, and also to choose a step. When choosing the step, the following regularities take place.

1. For a small atomic weight of the incident particle and small depths, the step is small (about 10-20), with increasing depth of observation it begins to increase.

2. With increasing atomic weight of the incident particle, the step accordingly increases, reaching several hundred and even thousands.

3. When the atomic weight of the flying particle increases, the step increases accordingly, reaching several hundred and even thousands.

4. The pitch greatly increases with a large atomic weight of the incident particle and a small target.

Table 2 – Dependence of the percentage of displacement of the left and right boundaries of the result area on the number of interactions for nitrogen in aluminum: a) $E_0=1000 \text{ keV}$; b) $E_0=800 \text{ keV}$; c) $E_0=500 \text{ keV}$; d) $E_0=200 \text{ keV}$; e) $E_0=100 \text{ keV}$

<i>h</i> *10 ⁴ , cm	B1,%	B2,%	N_n	B3,%
10	38	8	40	46
15	39	-8	35	3,1
20	43,5	-22	40	21,5
25	49	-33	45	16
30	55	-43	57	12
35	62,4	-53,85	65	8,55
40	71,66	-66,6	75	5,06
45	84,88	-82,86	95	2,06
-	- ,	a)		,
<i>h</i> *10 ⁴ , cm	B1,%	B2,%	Nn	B3,%
10	37	1	35	38
15	40,5	-15	35	25,2
20	46,5	-28	47	18,5
25	53,5	-40,7	63	12,8
30	62	-53,85	75	8,15
35	73,54	-68,9	95	4,64
	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	b)		.,
h^*10^4 , cm	B1,%	B2,%	Nn	B3,%
1	58	68	13	126
4	35,3	20	25	55,3
7	34	2	30	36
10	37	-11	38	26
13	41,5	-22,23	48	19,27
16	47,5	-33	54	14,5
19	54,3	-44,4	67	9,9
22	62	-55,75	75	6,25
25	73,3	-69	97	44,3
		c)		1 ·
<i>h</i> *10 ⁴ , cm	B1,%	B2,%	Nn	B3,%
1	38,6	38	15	76,6
3	30,2	6	24	36,2
5	34	-10	37	24
7	40,5	-24	45	16,5
9	5	-39,8	50	34,8
11	62,23	-65,5	75	3,27
12	69,87	-65,3	85	4,57
		d)		1
<i>h</i> *10 ⁴ , cm	B1,%	B2,%	Nn	B3,%
1	30,5	21,5	25	52
2	29,4	0,6	35	30
3	33,8	-12	43	21,8
	40,6	-25	50	15,6
4	,			
4 5	49,2	-39	60	10,2

Table 3 – Dependence of percentage of displacement of the left and right boundaries of the result area from the penetration depth for silver in aluminum: a) $E_0=1000 \text{ keV}$; b) $E_0=800 \text{ keV}$; c) $E_0=500 \text{ keV}$; d) $E_0=200 \text{ keV}$; e) $E_0=100 \text{ keV}$; b) $E_0=800 \text{ keV}$; c) $E_0=500 \text{ keV}$; d) $E_0=200 \text{ keV}$; e) $E_0=100 \text{ keV$

<i>h</i> *10 ⁴ , cm	h/λ	C1,%	C2,%	N_h	C3,%
1	13164	-1,37	12	110	10,63
3	52312	-15,4	20,2	270	4,8
5	119152	-25,3	28,1	480	2,8
7	241088	-31,192	32,56	993	1,368
9	499490	-30,415	30,9	2800	0,485
		a)			
<i>h</i> *10 ⁴ , cm	h/λ	C1,%	C ₂ ,%	N _h	С3,%
1	24110	-1,752	9,5	150	7,748
2	54588	-8,7	14	240	5,3
3	94062	-15,046	18,8	360	3,754
4	146836	-20,91	23,5	480	2,59
5	220484	-25,942	27,8	780	1,858
6	329673	-29,293	30,45	1280	1,157
7	507016	-29,507	30,1	2480	0,593
8	842620	-24,575	24,745	8000	0,17
		b)			
$h^{*}10^{4}$, cm	h/λ	C1,%	C2,%	Nh	C3,%
1	42461	-6,52	12,2	210	5,68
2	106987	-17,073	20,42	405	3,347
3	213796	-25,93	27,88	755	1,95
4	418665	-30,226	31.071	1800	0,845
5	952474	-23,23	23,342	11500	0,112
		c)			<u> </u>
h^*10^5 , cm	h/λ	C1,%	C2,%	N _h	C3,%
1	9200	3,5	9,6	85	13,1
4	43505	-7,57	13,4	210	5,83
7	91527	-15,84	19,52	350	3,68
10	160878	-22,93	25,3	520	2,37
13	266084	-28,37	30	860	1,63
16	438730	-30,934	31,82	1650	0,886
19	762930	-28,45	28,78	4600	0,33
		d)			
<i>h</i> *10 ⁵ , cm	h/λ	C1,%	C2,%	Nh	C3,%
1	20130	-0,6	9,5	133	8,9
3	74350	-11,82	16	305	4,24
5	156710	-20,79	23,5	525	2,71
7	288940	-27,77	29,5	900	1,73
9	522905	-31,107	31,86	1900	0,753
11	1020546	-27,316	27,54	6600	0,224

Some regularities appearing when finding the real domain of determination for the CPF, calculated depending on the penetration depth, are noted.

1. Calculations show that for a small atomic weight of the incident particle and small depths, the region of the result of the CPF as a function of *h* is near *h*, which corresponds to h/λ . When the depth of observation is increased, the result area shifts to a region of greater depths and narrows.

2. When the initial energy of the particle decreases (the incident particle is the same) at the same depth of observation, the resultant region shifts to a region of large depths and narrows.

3. When the depth of observation is increased for any incident particle, the result area shifts to the right.

4. Depending on the atomic number of the incident particle at the same value of the depth h, the result area shifts to a region of large depths.

5. When a large value of the atomic number of the projectile is the area of the result is shifted to larger depths relative to *h* corresponding to h/λ already at shallow depths.

To calculate CPF in the found area, you must specify a step. In this case, a certain N_h value was taken as a step, which was added to the current h

and the CPF was calculated at h, $h+N_h$, $h+2N_h$, . . . Let's note some regularities of behavior of a step.

1. For a small atomic weight of the flying particle the step is small, with increase in depth of observation it increases, and on the end of a run very strongly.

2. With decrease of tentative energy of a particle with the same depth of observation (the flying particle same) the step also increases.

3. With increasing atomic weight of the incident particle for one and the same depth of observation, the step increases first gradually, then very sharply.

Next, calculations of the concentration of radiation defects for various incident particles in aluminum have been made using the following formula:

$$C_k(E_0,h) = \int_{E_c}^{E_{2\max}} W(E_0,E_2,h) dE_2 , \qquad (4)$$

 E_2 – primary knocked-out energy, E_{2max} the maximum kinetic energy that the atom will receive, E_c – threshold energy, $W(E_0, E_2, h)$ – the spectrum of primary knocked-out atoms. The results of the calculations are presented in Tables 4-6.

Table 4 – Limits of the region of determination of the concentration of radiation defects for germanium in aluminum at $E_c=50 \text{ keV}$, $E_0=1000 \text{ keV}$

h*10 ⁻⁴ , cm	Cк, cm	E0, keV	no	n 1	τ
0,1	31452,9	1000	342	663	5″75
2	34640,8	900	10319	11772	1′26″
4	38790,1	800	22509	24628	4'10"
6	44060,6	700	36526	39213	7' 25"
8,1	51426,5	600	53795	57102	12′57
10,1	61077,3	500	73611	77333	19'32"
12	74085,3	400	96941	101215	29'03"
13	83450	350	111802	116424	36'55"
14	95400,5	300	129231	134213	44'33
14,3	99134,5	280	135104	140152	47′20
14,7	105238	260	143505	148774	53'42"
15,1	112049	240	152665	158192	59'
15,5	119653	220	162734	168361	1º03'
15,8	124508	200	171000	176816	1°09′
16,2	133078	180	183184	189101	1º14'
16,6	142065	160	197029	203203	1º23'
16,9	144496	140	208809	215170	1º30'
17,3	148840	120	226991	233671	1044'
17,6	135244	100	243135	250085	1°55′
18	99265,8	80	269617	277085	2º17'
18,1	48551,7	70	277471	284876	2º22'
18,3	0	60	295266	302961	2º33'

h*10 ⁴ , sm	С _к , ст ⁻¹	Eo, keV	no	n 1
0,1	55205,65	500	732	1177
2	68422,14	400	21344	23380
3	77960,77	350	34982	37597
3,9	88414,43	300	49461	52552
4,3	94041,72	280	56753	60141
4,7	100325,61	260	64696	68332
5	104745,65	240	71149	74955
5,4	112163,36	220	80531	84510
5,8	120392,95	200	90980	95309
6,1	125325,64	180	99669	105065
6,5	133914,22	160	112668	117351
6,9	142074,07	140	127742	132743
7,2	140336,23	120	140849	146091
7,6	134940,54	100	161665	167314
7,9	92994,21	80	180855	186858
8,1	49191,1	70	196123	202371
8,2	0	60	204751	211247

Table 5 – Limits of the region of determination of the concentration of radiation defects for germanium in aluminum at $E_c=50 \text{ keV}$, $E_0=500 \text{ keV}$

Table 6 – Limits of the region of determination of the concentration of radiation defects for germanium in aluminum at $E_c=50 \text{ keV}$, $E_0=200 \text{ keV}$

h*10 ⁴ , cm	Cк, cm	Eo, keV	no	n 1
0,1	123843,73	200	2374	3113
0,4	130916,49	180	11019	12529
0,7	137135,12	160	20901	22972
1,1	147583,01	140	36251	38951
1,4	147032,15	120	49806	53019
1,8	142423,51	100	71572	75422
2,1	98253,23	80	91756	96218
2,3	51800,91	70	107808	112501
2,5	0	60	126727	131688

Finding the region of the result of the concentration of radiation defects during ion irradiation made it possible to reveal the following regularities:

1. During the reduction of the initial energy of the primary particle, the range of the result area shifts to a region of greater depths, the values of the concentration of radiation defects increase.

2. Counting time and reaches several hours increases greatly with a large atomic weight of the flying particle and a small target.

3. Depending on the penetration depth, the initial and final values of the number of interactions increase, the interval of the result area $((n_0 \ n_1)$ also increases and shifts to the greater depths.

4. The interval of the result area is significantly shifted to the right and increases, the value of the

concentration at the maximum point and the concentration values themselves greatly increase with the atomic number of the incident particle.

Conclusion

Thus, the paper presents a mathematical model of a cascade-probability function with allowance for energy losses for ions, an algorithm for calculating CPF, an approximation of the interaction cross section, and approximation coefficients for indium in aluminum. Calculations of CPF for various incident particles in aluminum are performed, depending on the number of interactions and the penetration depth of the particles. The regularities in the behavior of the area of the CPF result and the step for calculation are revealed. A model for calculating the concentration of radiation defects is presented, calculations are performed, regularities in the behavior of the result area are obtained depending on various factors.

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